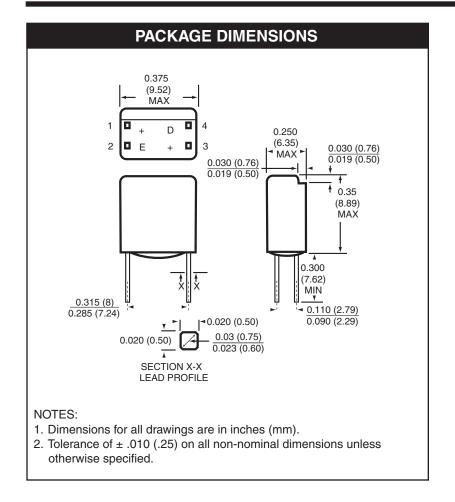
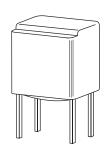
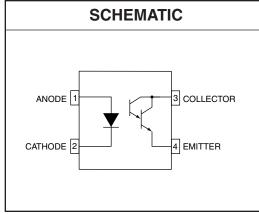
H24B1

H24B2







DESCRIPTION

The H24B series consists of a gallium arsenide infrared emitting diode coupled with a silicon photodarlington. The devices are housed in a low cost plastic package with lead spacing compatible with a dual in line package.

FEATURES

- 4-pin configuration
- · Small package size and low cost
- UL recognized file E50151
- · High current transfer ratio.



H24B1 H24B2

Parameter	Symbol	Rating	Unit	
Operating Temperature	T _{OPR}	-55 to +85	°C	
Storage Temperature	T _{STG}	-55 to +85	°C	
Soldering Temperature (Flow)	T _{SOL-F}	260 for 5 sec	°C	
EMITTER				
Power Dissipation at 25°C Ambient ⁽¹⁾	P _D	100	mW	
Continuous Forward Current	I _F	60	mA	
Reverse Voltage	V _R	4	V	
DETECTOR				
Power Dissipation 25°C Ambient ⁽²⁾	P _D	150	mW	
Collector to Emitter Voltage	V _{CEO}	30	V	
Emitter to Collector Voltage	V _{ECO}	7	V	
Continuous Forward Current	I _C	100	mA	

ELECTRICAL / OPTICAL CHARACTERISTICS (T _A =25°C)								
INDIVIDUAL COMPONENT CHARACTERISTICS								
Parameters	Test Conditions	Symbol	Min	Тур	Max	Units		
EMITTER								
Forward Voltage	I _F = 60 mA	V _F		_	1.7	V		
Reverse Current	V _R = 3.0 V	I _R		_	1	μΑ		
Reverse Breakdown Voltage	I _R = 10 μA	V _{(BR)R}	4			V		
Capacitance	V = 0 V, f = 1 MHz	С		30		pF		
DETECTOR								
Breakdown Voltage Collector to Emitter	$I_C = 1.0 \text{ mA}, I_F = 0$	BV _{CEO}	30			V		
Emitter to Collector	$I_E = 100 \mu A, I_F = 0$	BV _{ECO}	7			V		
Leakage Current Collector to Emitter	V _{CE} = 10 V, I _F = 0	I _{CEO}		5	100	nA		
Capacitance Collector to Emitter	V _{CE} = 5V, f = 1 MHz	C _{CE}		5		pF		

NOTE:

- 1. Derate power linearly 1.67 mW/°C above 25°C
- 2. Derate power linearly 2.5 mW/°C above 25°C



H24B1

H24B2

TRANSFER CHARACTERISTICS (T _A = 25°C Unless otherwise specified.)								
DC Characteristics	Test Conditions		Symbol	Min	Тур	Max	Units	
COUPLED	V -15VI -5mA	H24B1	CTR	1000			%	
DC current Transfer Ratio (note 1)	$V_{CE} = 1.5 \text{ V}, I_{F} = 5 \text{ mA}$	H24B2		400			70	
Saturation Voltage	$I_C = 2 \text{ mA}, I_F = 5 \text{ mA}$		V _{CE(SAT)}		0.8	1.0	V	
AC Characteristics	Test Conditions		Symbol	Min	Тур	Max	Units	
Turn-on Time	$I_C = 10$ mA, $V_{CE} = 10$ V $R_L = 100\Omega$		ton		105		μs	
Turn-off Time			toff		60		μs	
Turn-on Time	$I_F = 10$ mA, $V_{CC} = 5$ V $R_L = 1.0$ k Ω		ton		10		μs	
Turn-off Time			toff		700		μs	

ISOLATION CHARACTERISTICS							
Characteristic	Test Conditions	Symbol	Min	Тур	Max	Units	
Surge Isolation Voltage	1 Minute	V _{ISO}	6000			V _{peak}	
Steady-State Isolation Voltage	1 Minute	V _{ISO}	5300			V _{RMS}	
Isolation Resistance	V _{I-0} = 500VDC	R _{ISO}	10 ¹¹			Ohm	
Isolation Capacitance	V _{I-0} = 0, f = 1 MHz	C _{ISO}		0.5		pF	

NOTE:

^{1.} The current transfer ratio (I_C/I_F) is the ratio of the detector collector current to the LED input current with V_{CE} at 1.5 volts.

H24B1

H24B2

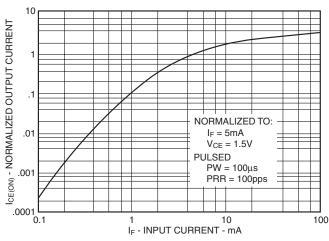


Fig. 1. Output Current vs. Input Current

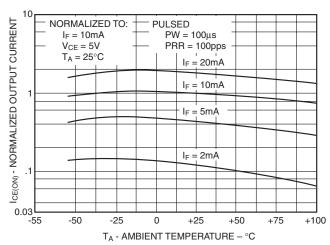


Fig. 2. Output Current vs. Temperature

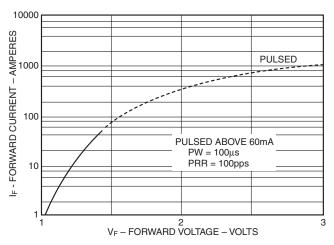


Fig. 3. Input Characteristics

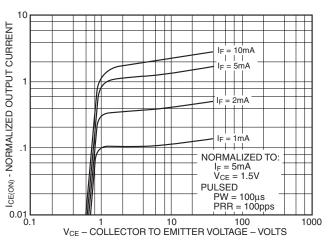


Fig. 4. Output Characteristics

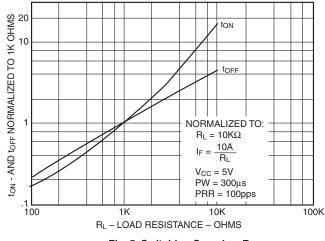


Fig. 5. Switching Speed vs RL

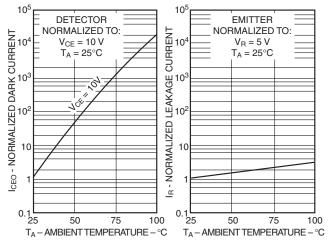


Fig. 6. Leakage Current vs. Temperature



H24B1

H24B2

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.